
	<h2>NTJD1155LT1G</h2>
	<p>Hersteller-Teilenummer: NTJD1155LT1G</p> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N/P-CH 8V 1.3A SOT-363</p> <p>Datenblätter:  NTJD1155LT1G.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 61370 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTJD1155LT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N/P-CH 8V 1.3A SOT-363
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	61370 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	400mW
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-88/SC70-6/SOT-363
Typ FET	N and P-Channel
FET-Merkmal	Standard
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	1.3A
Rds On (Max) @ Id, Vgs	175 mOhm @ 1.2A, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	-
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































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Sie können auch interessiert sein:

 <p>NTJD2152PT2 AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 8V 0.775A SOT-363</p>	 <p>NTJD3158CT1G O NTJD3158CT1G O</p>	 <p>NTJD2152PT2G AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 8V 0.775A SOT-363</p>	 <p>NTJD1155LT1 AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 8V 1.3A SOT-363</p>
 <p>NTJD2152PT4 AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 8V 0.775A SOT-363</p>	 <p>NTJD2152PT1G AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 8V 0.775A SOT-363</p>	 <p>NTJD3158CT2G AMI Semiconductor / ON Semiconductor MOSFET N/P-CH 20V SC88-6</p>	 <p>NTJD2152PT1 AMI Semiconductor / ON Semiconductor MOSFET 2P-CH 8V 0.775A SOT-363</p>

heiße Teile

Mehr

Contact us: Info@Y-IC.com

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